



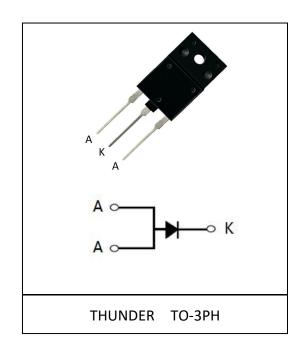
### Thunder High Power Products

# FRED Ultrafast Soft Recovery Diode, 80A

#### **Features:**

- Ultrafast Recovery
- 175°C operating junction temperature
- High frequency operation
- Low power loss, less RFI and EMI
- Low I<sub>R</sub> value
- High surge capacity
- Epitaxial chip construction

Product Summary				
VR	600 V			
lf(AV)	80A			
trr	32ns			



# **Description/Applications**

These diodes are optimized to less losses and EMI/RFI in high frequency power conditioning system. The soft recovery behavior of the diodes offers the need as snubber in most applications. These devices are ideally suited for HF welding power converters and other applications where the switching losses are not significant portion of the total losses.

## **Absolute Maximum Ratings**

Parameter	Symbol	Test Conditions	Values	Units
Repetitive peak reverse voltage	Vrrm		600	V
Continuous forward current	lf(AV)	Tc =110°C	80	
Single pulse forward current	IFSM	Tc =25°C	800	А
Maximum repetitive forward current	IFRM	Square wave, 20kHZ	160	
Operating junction	Тј		175	°C
Storage temperatures	Tstg		-55 to +175	°C

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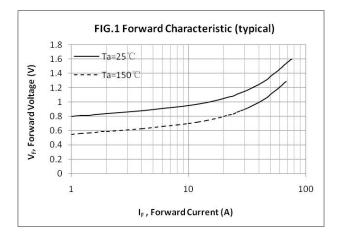
# Electrical characteristics (Ta=25°C unless otherwise specified)

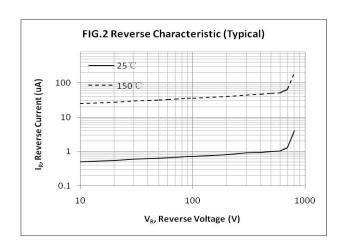
Parameter	Symbol	Test Conditions	Min	Тур.	Max.	Units	
Breakdown voltage	VBR,	Ir=100µA	600				
Blocking voltage	$V_R$	IK-100PA	000				
Forward voltage (Per Diode)	VF	IF=80A		1.45	1.80	V	
		IF=80A, Tj =125°C		1.35	1.70		
Reverse leakage current(Per Diode)		Vr= Vrrm			50		
	lr.	Tj=150°C, Vr=600V			500	μΑ	
Reverse recovery time(Per Diode)	trr	I <sub>F</sub> =0.5A, I <sub>R</sub> =1A, I <sub>RR</sub> =0.25A		55	80	nc	
	CIT	$I_F=1A, V_R=30V, di/dt = 200A/us$		32	50	ns	

#### Thermal characteristics

Paramter	Symbol	Тур	Units
Junction-to-Case	$R_{ heta JC}$	0.7	°C/W

# **Electrical performance (typical)**

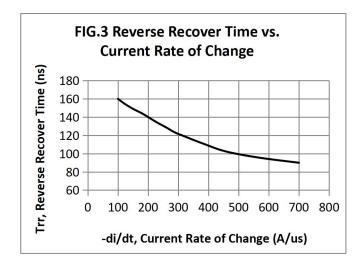


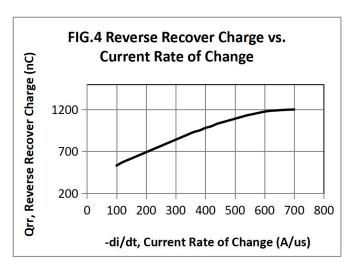


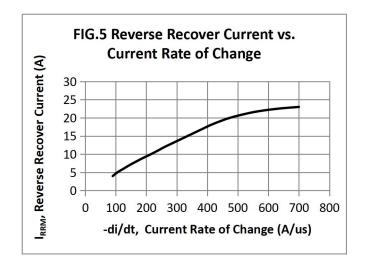
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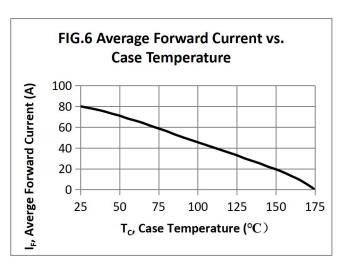


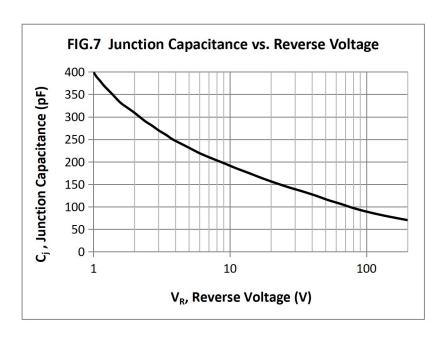












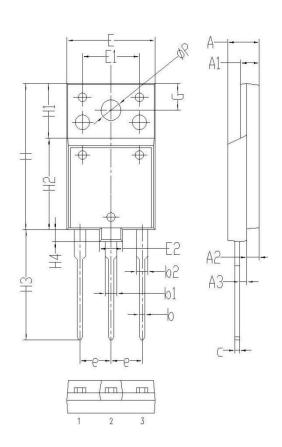
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# **Package Information**

#### TO-3PH PACKAGE



Symbol	Unit mm		
	Min	Тур	Max
Α	5.35	5.55	5.75
A1	2.80	3.00	3.20
A2	1.90	2.10	2.30
А3	1.10	1.30	1.50
b	0.65	0.75	0.85
b1	1.80	2.00	2.20
b2	1.80	2.00	2.20
С	0.70	0.90	1.10
е	5.25	5.45	5.65
Е	15.3	15.5	15.7
E1	9.80	10.0	10.2
E2	3.80	4.00	4.20
Н	24.3	24.5	24.7
H1	9.00	9.20	9.40
H2	15.1	15.3	15.5
Н3	18.5	19.0	19.5
H4	1.80	2.00	2.20
H5	4.80	5.00	5.20
G	4.3	4.5	4.7
ФР	3.40	3.60	3.80

#### **Notice**

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